

HiPerFRED

V_{RRM} = 300 V
 I_{FAV} = 10 A
 t_{rr} = 35 ns

High Performance Fast Recovery Diode

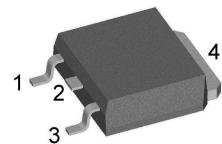
Low Loss and Soft Recovery

Single Diode

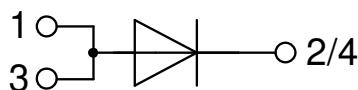
Part number

DPG10IM300UC

Marking on Product: PAOGUI



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-252 (DPak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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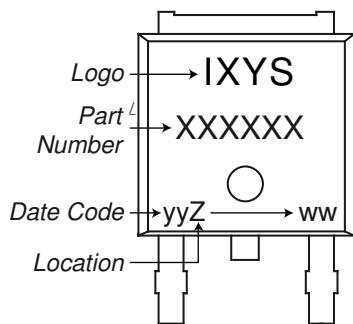
Fast Diode

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			300	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			300	V
I_R	reverse current, drain current	$V_R = 300 \text{ V}$ $V_R = 300 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1 0.06	μA mA
V_F	forward voltage drop	$I_F = 10 \text{ A}$ $I_F = 20 \text{ A}$ $I_F = 10 \text{ A}$ $I_F = 20 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 150^\circ\text{C}$		1.27 1.45 0.98 1.17	V V V V
I_{FAV}	average forward current	$T_C = 150^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 175^\circ\text{C}$		10	A
V_{F0} r_F	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 175^\circ\text{C}$		0.74 17.7	V $\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				2.3	K/W
R_{thCH}	thermal resistance case to heatsink			0.5		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		65	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		140	A
C_J	junction capacitance	$V_R = 150 \text{ V}$ $f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$	15		pF
I_{RM}	max. reverse recovery current		$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	3 5.5		A A
t_{rr}	reverse recovery time	$I_F = 10 \text{ A}; V_R = 200 \text{ V}$ $-di_F/dt = 200 \text{ A}/\mu\text{s}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$	35 45		ns ns

Package TO-252 (DPak)

Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal ¹⁾			20	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				0.3		g
F_c	mounting force with clip		20		60	N

¹⁾ I_{RMS} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.

Product Marking

Part description

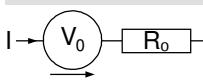
D = Diode
P = HiPerFRED
G = extreme fast
10 = Current Rating [A]
IM = Single Diode
300 = Reverse Voltage [V]
UC = TO-252AA (DPak)

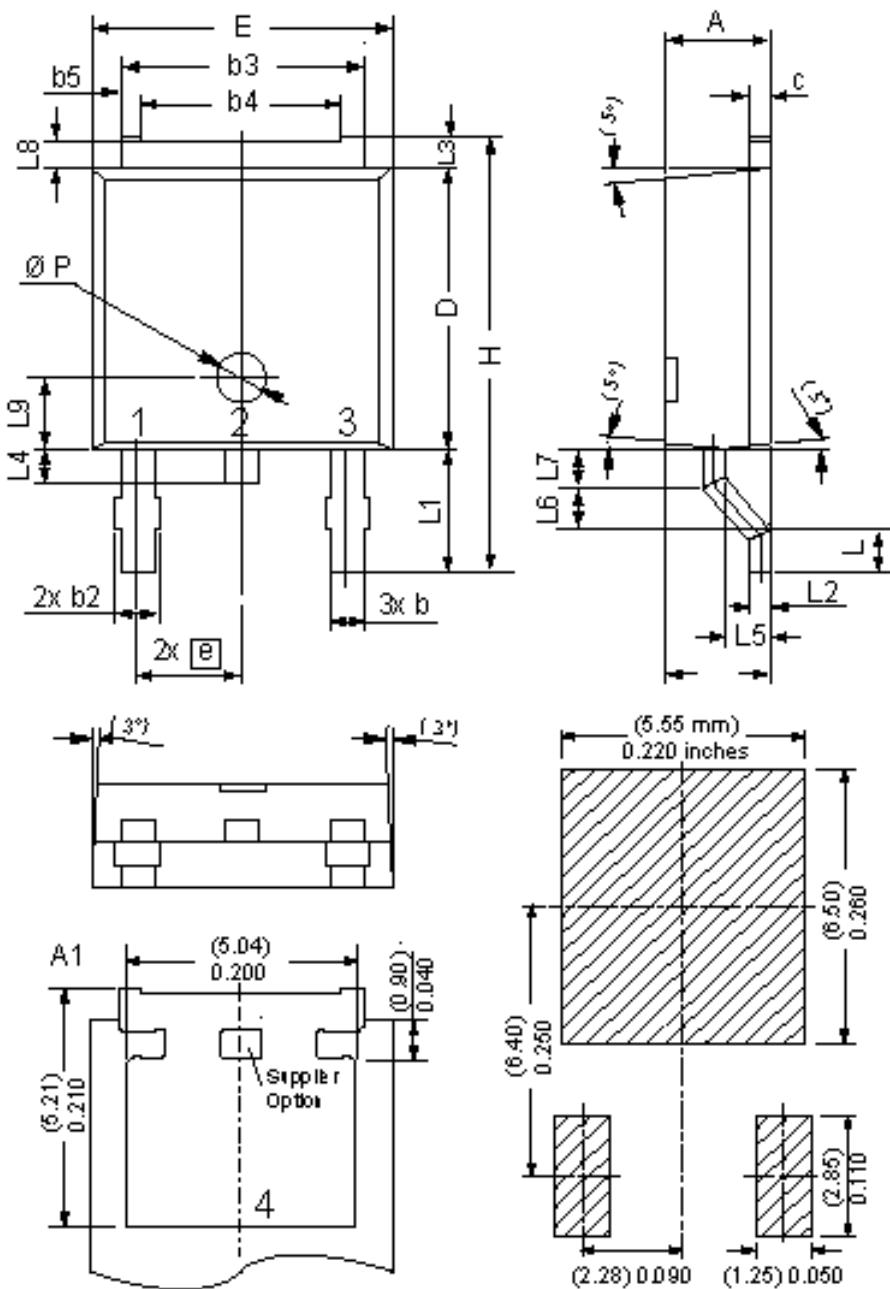
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DPG10IM300UC-TRL	PAOGUI	Tape & Reel	2500	505682
Alternative	DPG10IM300UC-TUB	PAOGUI	Tube	70	524908

Similar Part	Package	Voltage class
DPG10I300PA	TO-220AC (2)	300

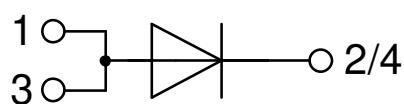
Equivalent Circuits for Simulation
^{*} on die level

 $T_{VJ} = 175^\circ\text{C}$

	Fast Diode	
$V_{0\ max}$	threshold voltage	0.74 V
$R_{0\ max}$	slope resistance *	14.5 mΩ

Outlines TO-252 (DPak)


Dim.	Millimeters		Inches	
	min	max	min	max
A	2.20	2.40	0.087	0.094
A ₁	2.10	2.50	0.083	0.098
b	0.66	0.86	0.026	0.034
b ₂	-	0.96	-	0.038
b ₃	5.04	5.64	0.198	0.222
b ₄	4.34 BSC	4.34 BSC	0.171 BSC	0.171 BSC
b ₅	0.50 BSC	0.50 BSC	0.020 BSC	0.020 BSC
c	0.40	0.86	0.016	0.034
D	5.90	6.30	0.232	0.248
E	6.40	6.80	0.252	0.268
e	2.10	2.50	0.083	0.098
H	9.20	10.10	0.362	0.398
L	0.55	1.28	0.022	0.050
L ₁	2.50	2.90	0.098	0.114
L ₂	0.40	0.60	0.016	0.024
L ₃	0.50	0.90	0.020	0.035
L ₄	0.60	1.00	0.024	0.039
L ₅	0.82	1.22	0.032	0.048
L ₆	0.79	0.99	0.031	0.039
L ₇	0.81	1.01	0.032	0.040
L ₈	0.40	0.80	0.016	0.031
L ₉	1.50 BSC	1.50 BSC	0.059 BSC	0.059 BSC
Ø P	1.00 BSC	1.00 BSC	0.039 BSC	0.039 BSC

 Recommended
min. foot print


Fast Diode
